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, 24小时加急出货

ZVN4306A

N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

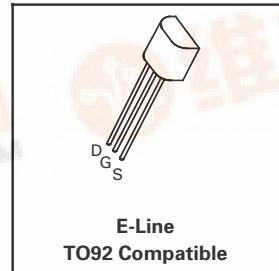
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FEATURES

- * 60 Volt V_{DS}
- * $R_{DS(on)} = 0.33\Omega$
- * Spice model available

APPLICATIONS

- * DC-DC convertors
- * Solenoids / relay drivers for automotive



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | VALUE | UNIT |
|--|---------------|-------------|------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Continuous Drain Current at $T_{amb}=25^\circ C$ | I_D | 1.1 | A |
| Practical Continuous Drain Current at $T_{amb}=25^\circ C$ | I_{DP} | 1.3 | A |
| Pulsed Drain Current | I_{DM} | 15 | A |
| Gate Source Voltage | V_{GS} | ± 20 | V |
| Power Dissipation at $T_{amb}=25^\circ C$ | P_{tot} | 850 | mW |
| Practical Power Dissipation at $T_{amb}=25^\circ C$ * | P_{totp} | 1.13 | W |
| Operating and Storage Temperature Range | $T_j:T_{stg}$ | -55 to +150 | °C |

*The power which can be dissipated assuming the device is mounted in a typical manner on a P.C.B. with copper equal to 1 inch square minimum

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS. |
|---|--------------|------|--------------|--------------|----------|---|
| Drain-Source Breakdown Voltage | BV_{DSS} | 60 | | | V | $I_D=1mA, V_{GS}=0V$ |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | 1.3 | | 3 | V | $I_D=1mA, V_{DS}=V_{GS}$ |
| Gate-Body Leakage | I_{GSS} | | | 100 | nA | $V_{GS}=\pm 20V, V_{DS}=0V$ |
| Zero Gate Voltage Drain Current | I_{DSS} | | | 10 100 | μA | $V_{DS}=60V, V_{GS}=0$ $V_{DS}=48V, V_{GS}=0V, T=125^\circ C(2)$ |
| On-State Drain Current(1) | $I_{D(on)}$ | 12 | | | A | $V_{DS}=10V, V_{GS}=10V$ |
| Static Drain-Source On-State Resistance (1)(2) | $R_{DS(on)}$ | | 0.22 0.32 | 0.33 0.45 | Ω | $V_{GS}=10V, I_D=3A$ $V_{GS}=5V, I_D=1.5A$ |
| Forward Transconductance (1)(2) | g_{fs} | 700 | | | mS | $V_{DS}=25V, I_D=3A$ |

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ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS. |
|--------------------------------------|--------------|------|------|------|------|--|
| Input Capacitance (2) | C_{iss} | | | 350 | pF | $V_{DS}=25\text{ V}, V_{GS}=0\text{V}, f=1\text{MHz}$ |
| Common Source Output Capacitance (2) | C_{oss} | | | 140 | pF | |
| Reverse Transfer Capacitance (2) | C_{rss} | | | 30 | pF | |
| Turn-On Delay Time (2)(3) | $t_{d(on)}$ | | | 8 | ns | $V_{DD}=25\text{V}, V_{GEN}=10\text{V}, I_D=3\text{A}$ |
| Rise Time (2)(3) | t_r | | | 25 | ns | |
| Turn-Off Delay Time (2)(3) | $t_{d(off)}$ | | | 30 | ns | |
| Fall Time (2)(3) | t_f | | | 16 | ns | |

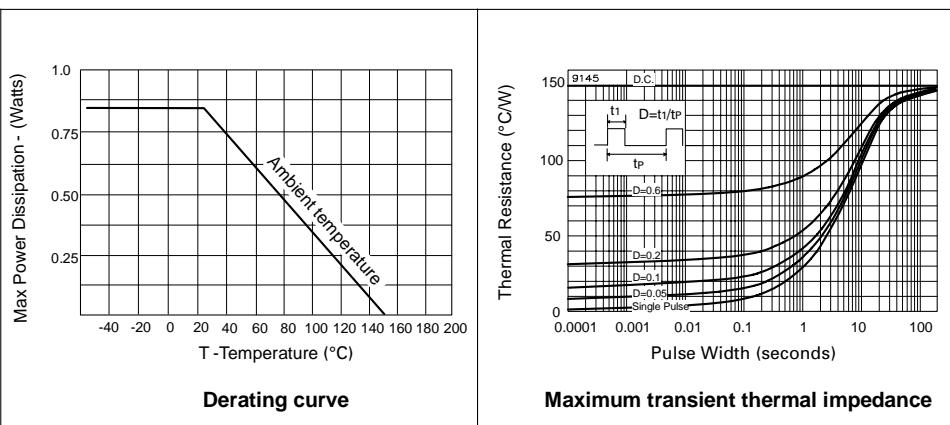
(1) Measured under pulsed conditions. Width=300μs. Duty cycle ≤2%

(2) Sample test.

(3) Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator

THERMAL CHARACTERISTICS

| PARAMETER | SYMBOL | MAX. | UNIT |
|---|-------------------------------------|-----------|--------------|
| Thermal Resistance: Junction to Ambient Junction to Case | $R_{th(j-amb)}$ $R_{th(j-case)}$ | 150 50 | °C/W °C/W |



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TYPICAL CHARACTERISTICS

